MSKSEMI















ESD

TVS

TSS

MOV

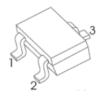
GDT

PLED

Broduct data sheet



NPN Silicon Epitaxial Planar Transistor





for switching and amplifier applications

- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

SOT-323

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	60	V
Collector Emitter Voltage	V_{CEO}	40	V
Emitter Base Voltage	V_{EBO}	6	V
Collector Current	I _C	200	mA
Total Power Dissipation	P _{tot}	200	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	°C

CLASSIFICATION OF hFE

RANGE	100-300	
MARKING	AM	
	-	

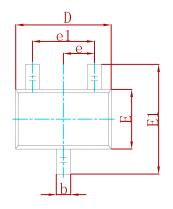


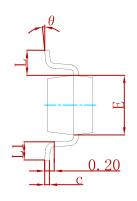
Characteristics at T_a = 25 °C

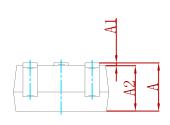
Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE} = 1$ V, $I_C = 0.1$ mA at $V_{CE} = 1$ V, $I_C = 1$ mA at $V_{CE} = 1$ V, $I_C = 10$ mA at $V_{CE} = 1$ V, $I_C = 50$ mA at $V_{CE} = 1$ V, $I_C = 100$ mA	h _{FE} h _{FE} h _{FE} h _{FE}	40 70 100 60 30	- 300 - -	
Collector Emitter Cutoff Current at V _{CE} = 30 V	I _{CES}	-	50	nA
Emitter Base Cutoff Current at V _{EB} = 3 V	I _{EBO}	-	50	nA
Collector Base Breakdown Voltage at $I_C = 10 \mu A$	V _{(BR)CBO}	60	-	V
Collector Emitter Breakdown Voltage at I _C = 1 mA	V _{(BR)CEO}	40	-	V
Emitter Base Breakdown Voltage at $I_E = 10 \mu A$	$V_{(BR)EBO}$	6	-	V
Collector Emitter Saturation Voltage at $I_C = 10$ mA, $I_B = 1$ mA at $I_C = 50$ mA, $I_B = 5$ mA	V _{CE(sat)}		0.2 0.3	V
Base Emitter Saturation Voltage at $I_C = 10$ mA, $I_B = 1$ mA at $I_C = 50$ mA, $I_B = 5$ mA	V _{BE(sat)}	0.65 -	0.85 0.95	V
Transition Frequency at $V_{CE} = 20 \text{ V}$, $I_{E} = 10 \text{ mA}$, $f = 100 \text{ MHz}$	f⊤	300	-	MHz
Collector Output Capacitance at $V_{CB} = 10 \text{ V}$, $f = 100 \text{ KHz}$	C _{ob}	ı	4	pF
Delay Time at $V_{CC} = 3 \text{ V}$, $V_{BE(OFF)} = 0.5 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = 1 \text{ mA}$	t _d	-	35	ns
Rise Time at $V_{CC} = 3 \text{ V}$, $V_{BE(OFF)} = 0.5 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = 1 \text{ mA}$	t _r	-	35	ns
Storage Time at $V_{CC} = 3 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = -I_{B2} = 1 \text{ mA}$	t _{stg}	-	200	ns
Fall Time at $V_{CC} = 3 \text{ V}$, $I_C = 10 \text{ mA}$, $I_{B1} = -I_{B2} = 1 \text{ mA}$	t _f	-	50	ns



PACKAGE MECHANICAL DATA

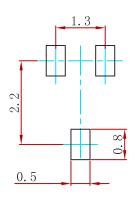






Symbol	Symbol Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650) TYP	0.026	6 TYP
e1	1.200	1.400	0.047	0.055
L	0.525	REF	0.021	REF
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

Suggested Pad Layout



Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MMBT3904W	SOT-323	3000



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